1 A very low V_F MEGA Schottky barrier rectifiers Rev. 02 — 22 March 2007 Pro

Product data sheet

Product profile 1.

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifiers with an integrated guard ring for stress protection, encapsulated in small and flat lead Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number	Package	Package	
	NXP	JEITA	
PMEG4010CEH	SOD123F	-	single
PMEG4010CEJ	SOD323F	SC-90	single

1.2 Features

- Forward current: $I_F \le 1 A$
- Reverse voltage: V_R ≤ 40 V
- Very low forward voltage
- Small and flat lead SMD plastic packages

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 2. **Quick reference data**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current	$T_{sp} \le 55 \ ^{\circ}C$	-	-	1	А
V _R	reverse voltage		-	-	40	V
V _F	forward voltage	I _F = 1 A	<u>[1]</u>	490	570	mV

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



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2. Pinning information

Pin	Description	Simplified outline Sy	ymbol
1	cathode	<u>[1]</u>	
2	anode	1 2	1 <u>-</u> 2 sym001
		001aab540	

[1] The marking bar indicates the cathode.

3. Ordering information

Table 4. Orderin	g information	l .	
Type number	Package		
	Name	Description	Version
PMEG4010CEH	-	plastic surface-mounted package; 2 leads	SOD123F
PMEG4010CEJ	SC-90	plastic surface-mounted package; 2 leads	SOD323F

4. Marking

Table 5. M	arking codes	
Type number	·	Marking code
PMEG4010C	EH	C9
PMEG4010C	EJ	EP

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5. Limiting values

Table 6. In accorda	Limiting values nce with the Absolute Maximum H	Rating System (IE)	C 60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	40	V
I _F	forward current	$T_{sp} \le 55 \ ^{\circ}C$	-	1	А
I _{FRM}	repetitive peak forward current	$\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25 \end{array}$	-	7	A
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms			
	PMEG4010CEH		-	9	А
	PMEG4010CEJ		-	10	А
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PMEG4010CEH		<u>[1]</u> _	375	mW
			[2] _	830	mW
	PMEG4010CEJ		<u>[1]</u> _	350	mW
			[2] _	830	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	PMEG4010CEH		[2] _	-	330	K/W
			[3] _	-	150	K/W
	PMEG4010CEJ		[2] _	-	350	K/W
			[3] _	-	150	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[4]</u>			
	PMEG4010CEH		-	-	60	K/W
	PMEG4010CEJ		-	-	55	K/W

 For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[4] Soldering point of cathode tab.

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7. Characteristics

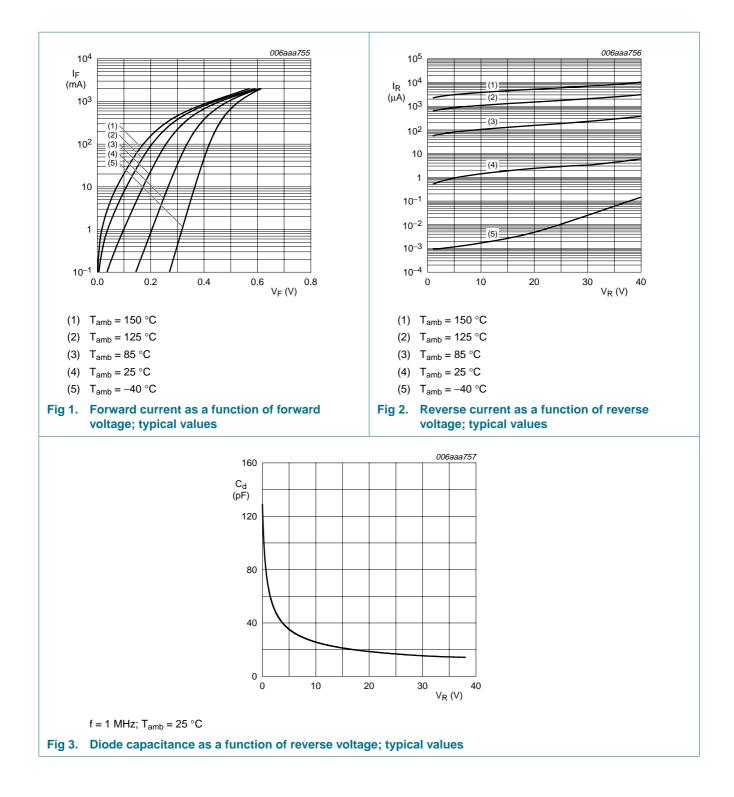
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage		<u>[1]</u>			
		I _F = 1 mA	-	210	240	mV
		I _F = 10 mA	-	270	310	mV
		I _F = 100 mA	-	340	390	mV
		I _F = 500 mA	-	420	490	mV
		I _F = 700 mA	-	450	520	mV
		I _F = 1 A	-	490	570	mV
I _R	reverse current	$V_R = 5 V$	-	0.8	-	μA
		V _R = 10 V	-	1.1	-	μA
		V _R = 40 V	-	6	50	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz	-	69	77	pF

PMEG4010CEH_PMEG4010CEJ_2

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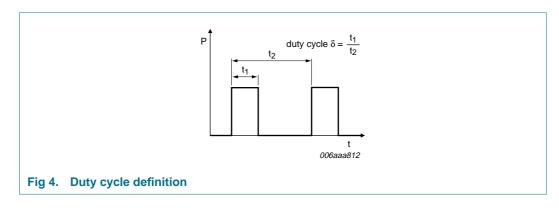
PMEG4010CEH; PMEG4010CEJ

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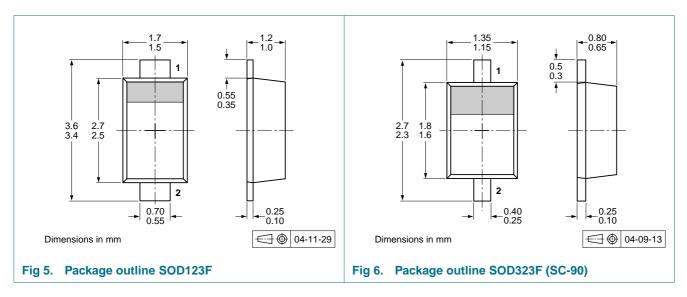


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8. Test information



9. Package outline



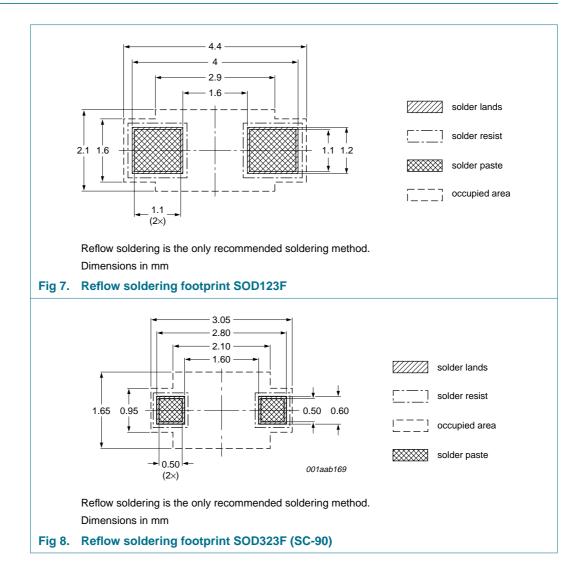
10. Packing information

Table 9.Packing methodsThe indicated -xxx are the last three digits of the 12NC ordering code.[1]					
Type number	Package	Description	Packing qua	antity	
			3000	10000	
PMEG4010CEH	SOD123F	4 mm pitch, 8 mm tape and reel	-115	-135	
PMEG4010CEJ	SOD323F				

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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11. Soldering



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12. Revision history

Table 10.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG4010CEH_PMEG4010CEJ_2	20070322	Product data sheet	-	PMEG4010CEJ_1
Modifications:		of this data sheet has bee delines of NXP Semicond	5	oly with the new
	 Legal texts 	have been adapted to the	new company name	where appropriate.
	 Type numb 	er PMEG4010CEH added	l	
	Section 1.1	"General description": an	nended	
	 Table 1 "Pression 	oduct overview": added		
	• Table 7 "Th	ermal characteristics": Tal	ole note 1 amended	
	Section 8 "	Test information": added		
PMEG4010CEJ_1	20060413	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PMEG4010CEH_PMEG4010CEJ_2

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